TOSHIBA Transistor Silicon PNP Triple Diffused Type

2SB1375

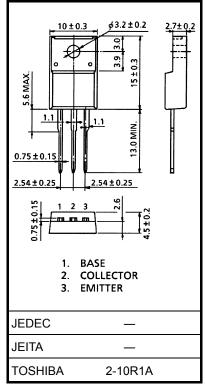
Audio Frequency Power Amplifier

Unit: mm

- Low saturation voltage: VCE (sat) = -1.5 V (max) (I_C = -2 A, I_B = -0.2 A)
- High power dissipation: $P_C = 25 \text{ W} (T_c = 25^{\circ}C)$
- Collector metal (fin) is covered with mold resin
- Complementary to 2SD2012

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-60	V	
Collector-emitter voltage		V _{CEO}	-60	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current		Ι _C	-3	А	
Base current		Ι _Β	-0.5	А	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	FC	25		
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to

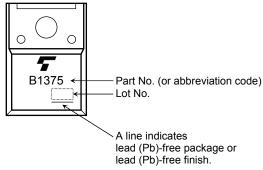
decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

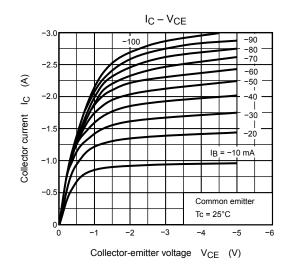
Electrical Characteristics (Tc = 25°C)

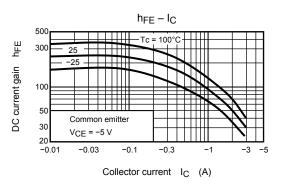
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0$	_	_	-10	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -7 V, I_C = 0$	_	_	-10	μA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = -50 mA, I _B = 0	-60	_	_	V
DC current gain	h _{FE (1)}	$V_{CE} = -5 V, I_C = -0.5 A$	100	_	320	
	h _{FE (2)}	$V_{CE} = -5 V, I_C = -2 A$	15	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -2 A, I _B = -0.2 A	_	-1.0	-1.5	V
Base-emitter voltage	V _{BE}	$V_{CE} = -5 V, I_C = -0.5 A$	_	-0.75	-1.0	V
Transition frequency	f _T	$V_{CE} = -5 V, I_C = -0.5 A$	_	9	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	50	_	pF

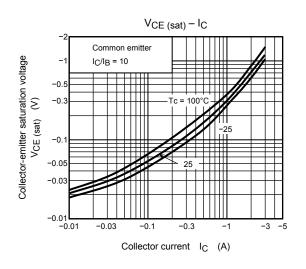
Marking

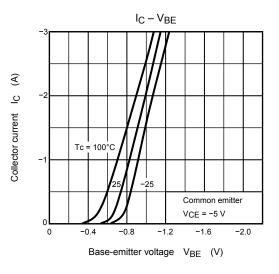


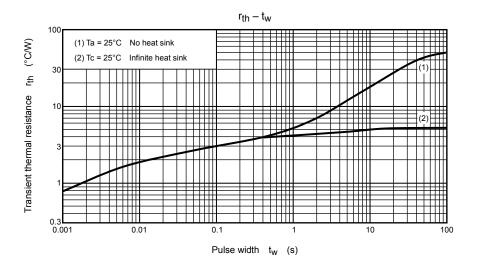
TOSHIBA



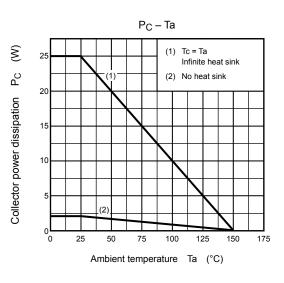








Safe Operating Area -10 IC max (pulsed)* ms⁴ $\overline{\mathsf{A}}$ IC max (continuous) Collector current I_C 10 ms 100 ms* DC operation Tc = 25°C -0.5 *: Single nonrepetitive pulse Tc = 25°C -0.3 Curves must be derated linearly with increase in temperature VCEO max -0.1 -3 -5 -10 -30 -50 -100 -200 -1 Collector-emitter voltage V_{CE} (V)



RESTRICTIONS ON PRODUCT USE

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